**Product data sheet** 

# 1. General description

Silicon Carbide Schottky diode in a TO220F-2L plastic package, designed for high frequency switched-mode power supplies.

### 2. Features and benefits

- · Highly stable switching performance
- High forward surge capability I<sub>FSM</sub>
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- Insulated package rated at 2500V RMS

## 3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage			-	-	650	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>h</sub> $\leq$ 25 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4		-	-	10	Α
Tj	junction temperature			-	-	175	°C
Static charac	teristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	1.5	1.7	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	1.8	2.1	V
Dynamic characteristics							

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q <sub>r</sub>		$I_F = 10 \text{ A; } dI_F/dt = 500 \text{ A/}\mu\text{s;}$ $V_R = 400 \text{ V; } T_i = 25 \text{ °C; } Fig. 7$	-	15	-	nC

# 5. Pinning information

## **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	[ <del>_</del> ]	K — A
2	А	anode		001aaa020
mb	n.c.	mounting base; isolated	TO220F-2L	

# 6. Ordering information

## **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
NXPSC10650X	-	Plastic single-ended through-hole package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220F	TO220F-2L			

# 7. Limiting values

### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	650	V
$V_{RWM}$	crest working reverse voltage		-	650	V
$V_R$	reverse voltage	DC	-	650	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>h</sub> $\leq$ 25 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4	-	10	Α
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 µs; T <sub>h</sub> ≤ 25 °C; squarewave pulse	-	20	Α
I <sub>FSM</sub>	non-repetitive peak	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse	-	50	Α
	forward current	$t_p$ = 10 $\mu$ s; $T_{j(init)}$ = 25 °C; square-wave pulse	-	450	Α
T <sub>stg</sub>	storage temperature		-55	175	°C
Tj	junction temperature		-	175	°C

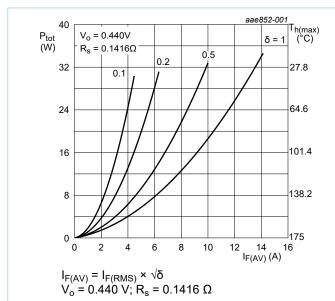


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

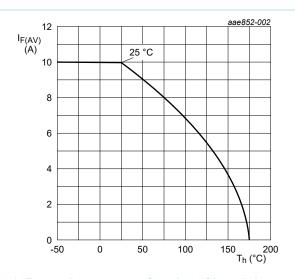
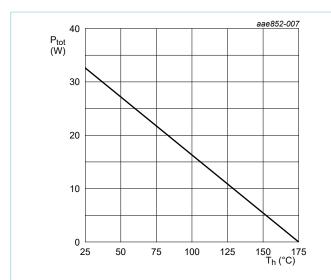


Fig. 2. Forward current as a function of heatsink temperature; maximum values

WeEn Semiconductors NXPSC10650X

## **Silicon Carbide Diode**





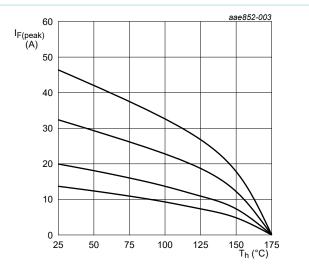


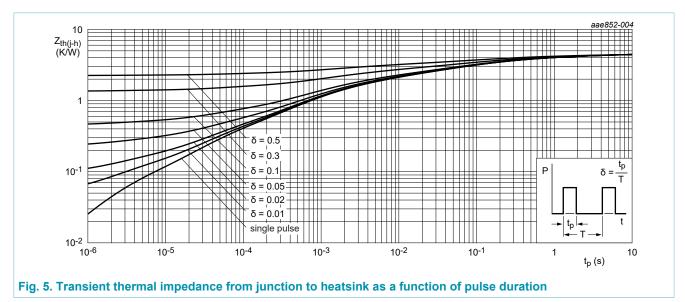
Fig. 4. Current derating as a function of heatsink temperature

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## 8. Thermal characteristics

**Table 5. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-h)</sub>	thermal resistance from junction to heatsink	with heatsink compound; Fig. 5	-	-	4.6	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



## 9. Isolation characteristics

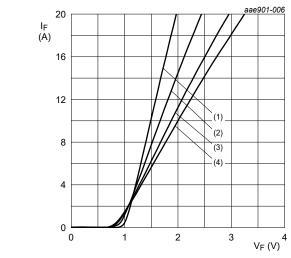
## **Table 6. Isolation characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>isol(RMS)</sub>	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; T <sub>h</sub> = 25 °C; RH = 65 %	-	-	2500	V

## 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.5	1.7	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	1.8	2.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C	-	-	250	μΑ
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 150 °C	-	-	800	μΑ
Dynamic cl	haracteristics			,		
Q <sub>r</sub>	recovered charge	$I_F = 10 \text{ A; } dI_F/dt = 500 \text{ A/}\mu\text{s;}$ $V_R = 400 \text{ V; } T_j = 25 \text{ °C; } Fig. 7$	-	15	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	300	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C	-	34	-	pF
		$f = 1 \text{ MHz}; V_R = 600 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	28	-	pF



(1)  $T_j$  = 25 °C; typical values (2)  $T_j$  = 100 °C; typical values (3)  $T_j$  = 150 °C; typical values (4)  $T_j$  = 175 °C; typical values



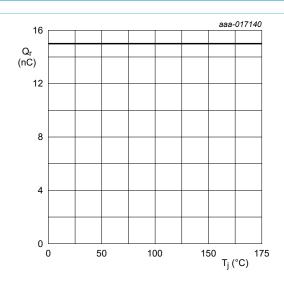


Fig. 7. Recovered charge as a function of junction temperature

# 11. Package outline

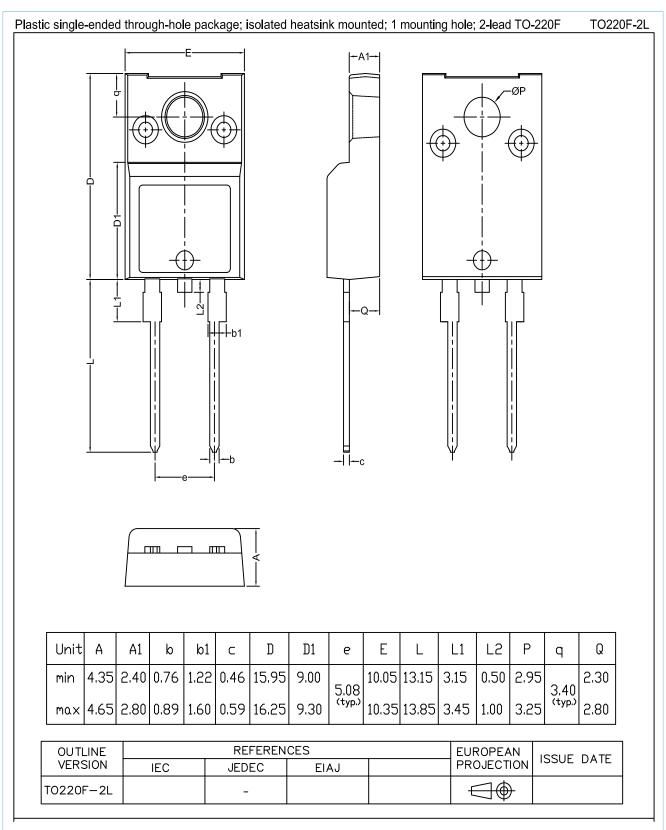


Fig. 8. Package outline TO220F-2L

# 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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For more information, please visit: http://www.ween-semi.com For sales office addresses, please send an email to: salesaddresses@ween-semi.com Date of release: 6 January 2017

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